



3.3V High Speed 2 : 4 Differential Mux/Demux

Features

- → 2:4 Differential Multiplexer/Demultiplexer
- → Bidirectional Operation
- → Can be used in
 - Single 1:4 Configuration
 - Dual 1:2 Configuration
 - Fan out 1:2 Configuration
- → High BW (1.2 GHz Typ)
- → Low RON and CON:
 - 13 Ω RON Typ
 - □ 9 pF CON Typ
- → ESD Performance (I/O Pins)
 - ±8-kV Contact Discharge (IEC61000-4-2)
 - ^D 2-kV Human Body Model per JESD22-A114E (to GND)
- → ESD Performance (All Pins)
 - 2-kV Human Body Model per JESD22-A114E
- → Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- → Halogen and Antimony Free. "Green" Device (Note 3)
- → For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/
- → Package: 20-pin (TQFN) (3 x 3 mm, 0.4 mm pitch)

Applications

- → Desktop/Notebooks Computers
- → DisplayPort Auxiliary Channel Multiplexing
- → DDC
- → UART
- → LSRX/LSTX for USB4/TBT
- → USB 2.0 Multiplexing
- → Netbooks/eBooks/Tablets

Description

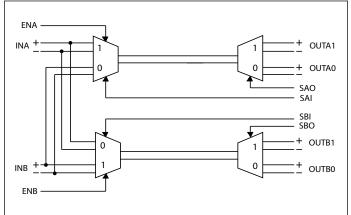
The PI3DBS3224 is a 2:4 bidirectional multiplexer for highspeed differential and single ended signal applications (up to 720 Mbps). The PI3DBS3224 can be used in a 1:4 or dual 1:2 multiplexer/demultiplexer configuration. The PI3DBS3224 offers a high BW of 1.2 GHz with channel RON of 13 Ω (Typ).

The PI3DBS3224 can also be used to fan out a differential or single ended signal pair to two ports simultaneously (fan-out configuration). The BW performance is lower in this configuration.

The PI3DBS3224 operates with a 3 to 3.6V power supply. It features ESD protection of up to ±8-kV contact discharge and 2-kV Human Body Model on its I/O pins.

The PI3DBS3224 provides fail-safe protection by isolating the I/O pins with high impedance when the power supply (V_{CC}) is not present.

Block Diagram



Notes:

PI3DBS3224 Document Number DS41709 Rev 2-2

^{1.} No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

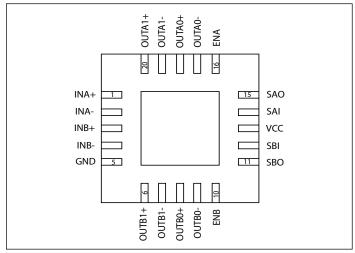
^{2.} See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



A product Line of Diodes Incorporated

PI3DBS3224

Pin Configuration



Pin Description

Pin #	Pin Name	І/О Туре	Description	
14	SAI	Input	Control Input	
15	SAO	Input	Control Input	
12	SBI	Input	Control Input	
11	SBO	Input	Control Input	
16	ENA	Input	Enable	
1	INA+	I/O	Input A	
2	INA-	I/O	Input A	
10	ENB	Input	Enable	
3	INB+	I/O	Input B	
4	INB-	I/O	Input B	
9	OUTB0-	I/O	Output B0	
8	OUTB0+	I/O	Output B0	
7	OUTB1-	I/O	Output B1	
6	OUTB1+	I/O	Output B1	
5	GND	Ground	Ground	
13	VCC	Power	Power Supply	
17	OUTA0-	I/O	Output A0	
18	OUTA0+	I/O	Output A0	
19	OUTA1-	I/O	Output A1	
20	OUTA1+	I/O	Output A1	





Function Table

ENA, ENB	OUTA0	OUTA1	OUTB0	OUTB1
00	Hi-Z	Hi-Z	Hi-Z	Hi-Z
01	Hi-Z	Hi-Z	-	-
10	-	-	Hi-Z	Hi-Z
11	-	-	-	-

SAI, SAO, SBI, SBO	OUTA0	OUTA1	OUTB0	OUTB1
0000	INB	-	INA	-
0001	INB	-	-	INA
0010	INB	-	INB	-
0011	INB	-	-	INB
0100	-	INB	INA	-
0101	-	INB	-	INA
0110	-	INB	INB	-
0111	-	INB	-	INB
1000	INA	-	INA	-
1001	INA	-	-	INA
1010	INA	-	INB	-
1011	INA	-	-	INB
1100	-	INA	INA	-
1101	-	INA	-	INA
1110	-	INA	INB	-
1111	-	INA	-	INB





Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

Storage Temperature65°C to+155°C
Supply Voltage to Ground Potential0.3V to+4.0V
DC Input Voltage0.3V to+4.3V
DC Output Current
Power Dissipation

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics over Operating Range

For Single 1:4 or Dual 1:2 configurations. $T_A = -40^{\circ}$ C to 85°C, Typical values are at Vcc = 3.3V, $T_A = 25^{\circ}$ C (unless otherwise noted)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
VIK	Digital input clamp voltage	$V_{CC} = 3.6 \text{ V}, I_1 = -18 \text{ mA}$	-1.2	-0.9		V
I _{IN}	Digital input leakage current	$V_{\rm CC}$ = 3.6 V, $V_{\rm IN}$ =0 to 3.6 V			±2	μΑ
I _{OZ} ⁽³⁾		$V_{CC} = 3.6 \text{ V}, V_0 = 0 \text{ V}$ to $3.6 \text{ V}, V_I = 0 \text{ V}$, Switch OFF			±2	μΑ
Ioff	Power off leakage current	$V_{CC} = 0$ V, $V_{IN} = V_{CC}$ or GND, $V_{I/O} = 0$ V to 3.6 V			± 8	μΑ
Icc	Supply current	$V_{CC} = 3.6$ V, $I_{1/0} = 0$, Switch ON or OFF		70	130	μΑ
CIN	Digital input capacitance	$V_{CC} = 3.3 \text{ V}, V_{IN} = V_{CC} \text{ or } \text{GND}$		3	5	pF
CI/O(OFF)	OFF capacitance	V_{CC} = 3.3 V, $V_{I/O}$ = 3.3V or 0, f = 10MHz, Switch OFF		6	7	pF
CI/O(ON)	ON capacitance	$V_{CC} = 3.3 \text{ V}, V_{I/O} = 3.3 \text{ V} \text{ or } 0, \text{f} = 10 \text{MH}_{Z}, \text{ Switch}$ ON		9	10	pF
		$V_{CC} = 3.6 \text{ V}, V_I = V_{CC}, I_O = -30 \text{ mA}$		13	19	Ω
r _{on}	ON state resistance	$V_{CC} = 3.3 \text{ V}, V_I = 0.5 \text{ V}, I_O = -30 \text{ mA}$		10		Ω
Δron	ON state resistance match between channel	$V_{\rm CC} = 3$ V, $V_{\rm I} = 0$ to $V_{\rm CC}$, $I_{\rm O} = -30$ mA		2	2.5	Ω
ron(flat)	ON state resistance flatness	$V_{\rm CC}\!=3$ V, $V_{\rm I}\!=1.5$ V and $V_{\rm CC},$ $I_{\rm O}\!=\!-30$ mA		4	6	Ω

Notes:

 V_{IN} and I_{IN} refer to control inputs. $V_{\text{I}}, V_{\text{O}}, I_{\text{I}}$ and I_{O} refer to data pins. 1

2. All typical values are at V_{CC} = 3.3V (unless otherwise noted), T_A = 25 °C.

3. For I/O ports, the parameter Ioz includes the input leakage current.





Dynamic Characteristics

For Single 1:4 or Dual 1:2 configurations. $T_A = -40^{\circ}$ C to 85°C, Typical values are at Vcc = $3.3V \pm 10\%$ and $T_A = 25^{\circ}$ C (unless otherwise noted)

Symbol	Parameter	Test Condition	Тур.	Unit
BW	Bandwidth	$R_{\rm L} = 50 \ \Omega$, Switch ON	1.2	GHz
O _{ISO}	OFF Isolation	$R_L = 50 \Omega$, $f = 250 MH_Z$	-30	dB
X _{TALK}	Crosstalk	$R_L = 50 \Omega$, $f = 250 MH_Z$	-35	dB

Switching Characteristics

For Single 1:4 or Dual 1:2 configurations. Over operating range, $T_A = -40^{\circ}C$ to 85°C, Vcc = 3.3V ± 10%, GND = 0V (unless otherwise noted)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
$t_{pd}^{(1)}$		$R_L = 50 \Omega, C_L = 2 pF$		50		ps
t _{on}	SAI/SAO/SBI/SBO to OUTAx/OUTBx	$R_{\rm L} = 50 \ \Omega, \ C_{\rm L} = 2 \ pF$		40	100	ns
t _{off}	SAI/SAO/SBI/SBO to OUTAx/OUTBx	$R_{\rm L} = 50 \ \Omega, \ C_{\rm L} = 2 \ pF$		20	30	ns
t _{sk(0)} ⁽²⁾		$R_{\rm L} = 50 \ \Omega, \ C_{\rm L} = 2 \ pF$		40		ps
$t_{sk(p)}^{(3)}$		$R_{\rm L} = 50 \ \Omega, \ C_{\rm L} = 2 \ pF$		40		ps

Notes:

The propagation delay is the calculated RC time constant of the typical ON-State resistance of the switch and the specified load capacitance when driven by an 1. ideal voltage source (zero output impedance).

Output skew between center channel and any other channel. 2.

Skew between opposite transitions of the same output ($|t_{PHL} - t_{PLH}|$). 3.





DC Electrical Characteristics over Operating Range

For fan-out 1:2 configurations. $T_A = -40^{\circ}$ C to 85° C, Typical values are at Vcc = 3.3V, $T_A = 25^{\circ}$ C (unless otherwise noted)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vik	Digital input clamp voltage	$V_{CC} = 3.6 \text{ V}, I_1 = -18 \text{ mA}$	-1.2	-0.9		V
Iin	Digital input leakage current	$V_{\rm CC} = 3.6$ V, $V_{\rm IN} = 0$ to 3.6 V			±2	μΑ
I _{OZ} ⁽³⁾		$V_{CC} = 3.6 \text{ V}, V_0 = 0 \text{ V}$ to 3.6 V, $V_1 = 0 \text{ V}$, Switch OFF			±2	μΑ
Ioff	Power off leakage current	$V_{CC} = 0 V$, $V_{IN} = V_{CC}$ or GND, $V_{I/0} = 0 V$ to 3.6 V			±8	μΑ
Icc	Supply current	$V_{CC} = 3.6 \text{ V}, I_{1/0} = 0$, Switch ON or OFF		70	130	μΑ
CIN	Digital input capacitance	$V_{CC} = 3.3 \text{ V}, V_{IN} = V_{CC} \text{ or } \text{GND}$		3	5	pF
CI/O(OFF)	OFF capacitance	V_{CC} = 3.3 V, $V_{I/O}$ = 3.3V or 0, f = 10MHz, Switch OFF		6	7	pF
CI/O(ON)	ON capacitance	$V_{CC} = 3.3 \text{ V}, V_{1/0} = 3.3 \text{ V} \text{ or } 0, \text{f} = 10 \text{ MHz},$ Switch ON		12	13	pF
r _{on}	ON state resistance	$V_{CC} = 3.6 \text{ V}, V_I = V_{CC}, I_O = -30 \text{ mA}$		13	19	Ω
Δr_{on}	ON state resistance match be- tween channel	$V_{\rm CC}$ = 3 V, $V_{\rm I}$ = 0 to $V_{\rm CC}$, $I_{\rm O}$ = -30 mA		2	2.5	Ω
ron(flat)	ON state resistance flatness	$V_{\rm CC}\!=\!3$ V, $V_{\rm I}\!=\!1.5$ V and $V_{\rm CC}, {\rm Io}\!=\!-30$ mA		4	6	Ω

Notes:

 V_{IN} and I_{IN} refer to control inputs. V_I , V_O , I_I and I_O refer to data pins. 1.

All typical values are at $V_{CC} = 3.3V$ (unless otherwise noted), $T_A = 25$ °C. 2.

3. For I/O ports, the parameter I_{OZ} includes the input leakage current.

Dynamic Characteristics

For fan-out 1:2 configurations. $T_A = -40^{\circ}$ C to 85°C, Typical values are at Vcc = $3.3V \pm 10\%$ and $T_A = 25^{\circ}$ C (unless otherwise noted)

Symbol	Parameter	Test Condition	Тур.	Unit
BW	Bandwidth	$R_L = 50 \Omega$, Switch ON	500	MHz
O _{ISO}	OFF Isolation	$R_{L} = 50 \Omega, f = 250 MH_{Z}$	-30	dB
X _{TALK}	Crosstalk	$R_{L} = 50 \Omega, f = 250 MH_{Z}$	-35	dB





Switching Characteristics

For fan-out 1:2 configuration. Over operating range, $T_A = -40^{\circ}$ C to 85°C, Vcc = 3.3V ± 10%, GND = 0V (unless otherwise noted)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
$t_{pd}^{(1)}$		$R_L = 50 \Omega, C_L = 2 pF$		140		ps
t _{on}	SAI/SAO/SBI/SBO to OUTAx/OUTBx	$R = 50 \ \Omega, \ C_L = 2 \ pF$		40	100	ns
t _{OFF}	SAI/SAO/SBI/SBO to OUTAx/OUTBx	$R_{LL} = 50 \Omega, C_L = 2 pF$		20	30	ns
t _{sk(0)} (2)		$R_L = 50 \Omega, C_L = 2 pF$		60		ps
$t_{sk(p)}^{(3)}$		$R_L = 50 \Omega, C_L = 2 pF$		60		ps

Notes:

The propagation delay is the calculated RC time constant of the typical ON-State resistance of the switch and the specified load capacitance when driven by an 1. ideal voltage source (zero output impedance).

Output skew between center channel and any other channel. 2.

Skew between opposite transitions of the same output ($|t_{PHL} - t_{PLH}|$). 3.

DC Electrical Characteristics over Operating Range

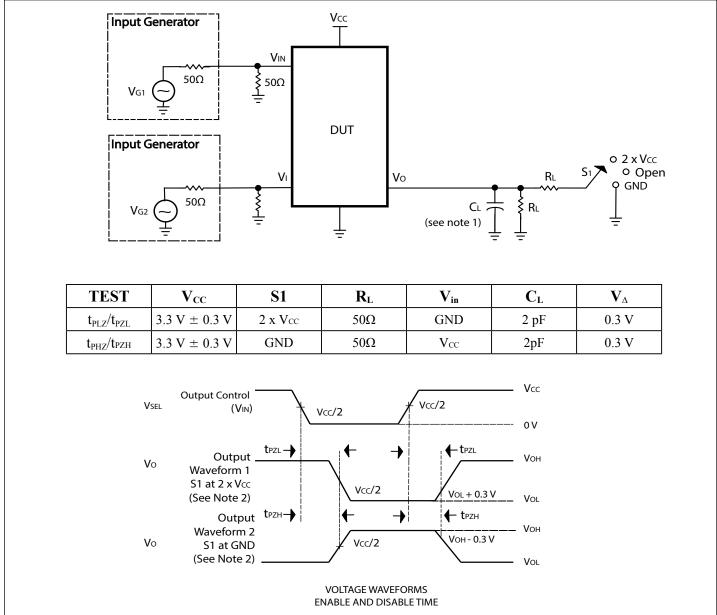
 $T_A = -40^{\circ}C$ to 85°C, Typical values are at Vcc = 3.3V, $T_A = 25^{\circ}C$

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
VIO	Analog I/O voltage		0		Vcc	V
VIH	High level input control voltage	ENx, SAx, SBx Pins	0.75Vcc		Vcc	V
VIL	Low level input control voltage	ENx, SAx, SBx Pins	0		0.6	V
Vcc	Supply voltage		3.0		3.6	V





Test Circuit For Electrical Characteristics



Notes:

C_L includes probe and jig capacitance. 1.

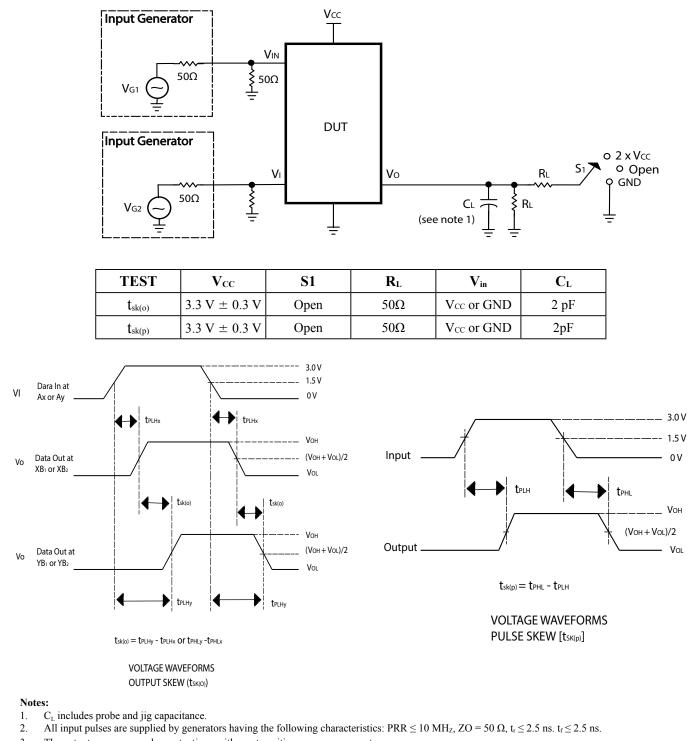
Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. 2.

- Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: $PRR \le 10 \text{ MH}_2$, $ZO = 50 \Omega$, $t_r \le 2.5 \text{ ns.}$ $t_f \le 2.5 \text{ ns.}$ 3.
- 4. The outputs are measured one at a time, with one transition per measurement.
- 5. t_{PLZ} and t_{PHZ} are the same as $t_{\text{OFF}}.$
- 6. t_{PZL} and t_{PZH} are the same as $t_{\text{ON}}.$





Test Circuit For Electrical Characteristics







Part Marking

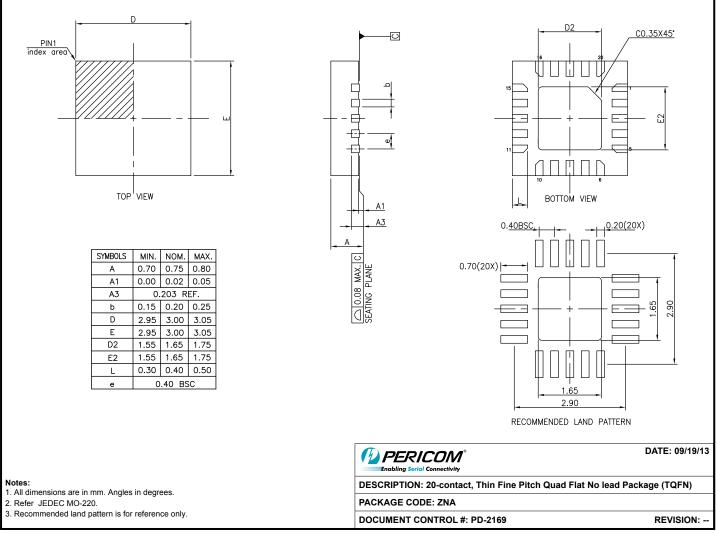


YY: Year WW: Workweek 1st X: Assembly Code 2nd X: Fab Code





Packaging Mechanical: 20-TQFN (ZNA)



13-0240

For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Code	Packaging Code	Package Description
PI3DBS3224ZNAEX	ZNA	20-contact, Thin Fine Pitch Quad Flat No Lead Package (TQFN)
NT 4		

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm

antimony compounds. 4. E = Pb-free and Green

5. X suffix = Tape/Reel





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